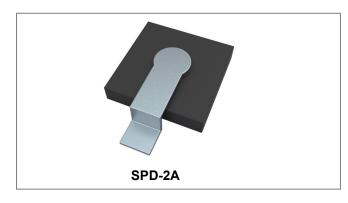


61SPB045/A

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# 61SPB045/A Power Surface Mount Schottky Rectifier



#### Features

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- Baseplate: Pure Sn plated; Terminals: Pure Sn plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Schematic & Pin Configuration



#### **Applications**

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> Vr	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =116°C, rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	860	A
Non-Repetitive Avalanche Energy	Eas	TJ=25℃,I <sub>AS</sub> =8.0A, L=1.7mH	54	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decaying linearly to 0 in 1µsec Frequency limited by $T_J$ max. $V_A{=}1.5$ $\times V_R$	8.0	А

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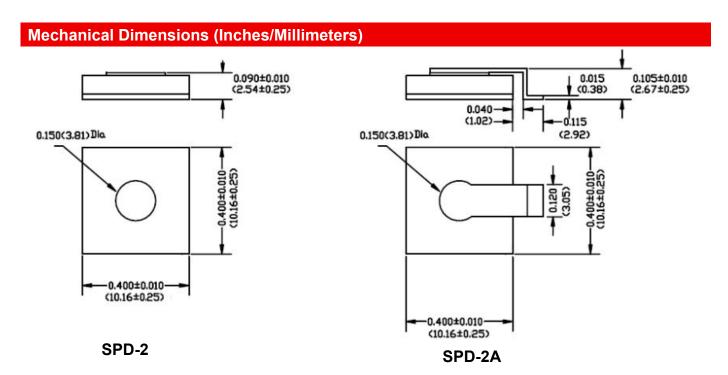
## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25 °C	0.59	0.66	V
	V <sub>F2</sub>	@ 60A, Pulse, T <sub>J</sub> = 125 °C	0.52	0.59	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ , Pulse, T <sub>J</sub> = 25 °C	0.03	1.2	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ , Pulse, T <sub>J</sub> = 125 °C	6	45	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \circ C$ $f_{SIG} = 1MHz$	2200	2400	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.37	°C/W
Approximate Weight	wt	-	1.1	g



### Suffix "R" Denotes Reversed Polarity

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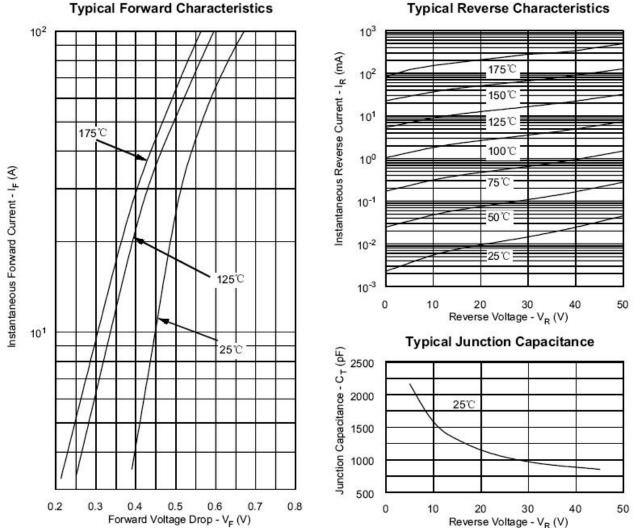


# 61SPB045/A

RoHS

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### **Ratings and Characteristics Curves**



#### **Typical Reverse Characteristics**

## **Ordering Information**

Device	Package	Shipping	
61SPB045(A)	SPD-2A(Pb-Free)	100pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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